



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

**OHTAKE, Fumio et al.**

Group Art Unit: **2814**

Serial No.: **09/749,590**

Examiner: **MAI, Anh D.**

Filed: **December 28, 2000**

P.T.O. Confirmation No.: **4831**

For: **SEMICONDUCTOR DEVICE HAVING GATE ELECTRODES WITH POLYMETAL  
STRUCTURE OF POLYCRYSTALLINE SILICON FILMS AND METAL FILMS (as  
amended)**

**AMENDMENT UNDER 37 CFR §1.111**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

September 8, 2003

Sir:

In response to the Office Action dated May 7, 2003, please amend the above-identified application  
as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this  
paper.

**Remarks/Arguments** begin on page 8 of this paper.

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